





# Elemental Scientific

# HNO<sub>3</sub>

# Automated Analysis of Semiconductor Grade HNO<sub>3</sub> with prep*FAST* S and NexION<sup>®</sup> 5000 ICPMS

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#### Introduction

Advances in semiconductor technology and decreasing tolerances in microchip design require simultaneous improvements in both chemical purity and fabrication. As manufacturers move to <10 nm geometry, while seeking improved yield, the chemicals and process reagents must maintain minimal trace metal contamination. The demand for lower detection limits in reagents requires new approaches to sample handling and trace elemental analysis within the fab and throughout the supply chain.

Nitric Acid is widely utilized in the semiconductor industry as a cleaning agent. The reduction of potential contamination of silicon wafers during the cleaning process is crucial as trace metal, particulate and organic contaminants can alter the functionality

of the semiconductors. At the ppt level, environmental contaminants are difficult to control and can easily contaminate a HNO<sub>3</sub> sample if not properly handled.

The prepFAST S ultraclean sample preparation and introduction system minimizes contamination from environment and sample handling, enabling semiconductor manufacturers and laboratories to easily analyze these critical samples. The prepFAST S features inline, automated calibration and dilution technology that automates sample and standard preparation. Samples are analyzed directly from their original containers in an exhausted and fully enclosed environment, eliminating manual sampling errors and operator variability and providing sub-ppt detection limits for critical semiconductor elements.



Figure 1. prepFAST S.



#### prep*FAST* S

The prepFAST S utilizes a robust PFA probe, CTFE AutoAlign Arm, and sealed PTFE vertical probe drive assembly combined with high-purity, chemically conditioned fluoropolymer flow paths to minimize contamination and maximize chemical resistance. When combined with an exhausted, enclosed sample environment, these features allow automated dilution, acidification, and spiking of concentrated semiconductor chemicals resulting in high-quality calibrations and accurate, precise determination of background equivalent concentrations and detection limits.

Calibrations are generated by automatically spiking from an enclosed multi-element stock standard using either automated

inline method of standard addition (MSA) or external calibration for over 50 elements that are typically controlled in semiconductor manufacturing processes. When combined with the interference reduction modes and multi-quadrupole functionality of the NexION 5000 ICPMS, the result is low to sub-ppt calibrations.

For sample analysis, the prepFAST S allows automatic dilution by volume or weight for direct analysis of concentrated chemicals from their original sample vessels. This feature eliminates sample contamination caused by manual dilution into a secondary container and significantly reduces operator exposure to concentrated and hazardous chemicals.

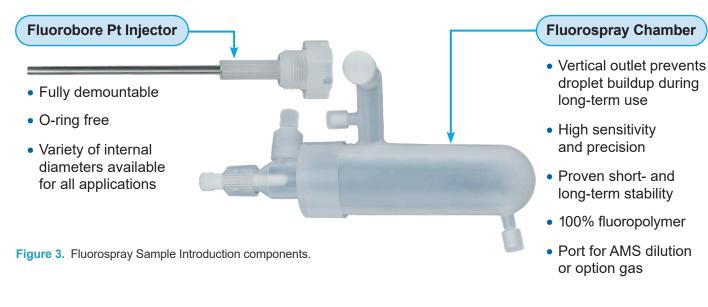
#### prep*FAST* S **Electronics in Rear Plenum UPW Polishing Columns** UPW is used as carrier, diluent, SampleSense Valve and rinse to control background levels and improve detection limits Automatically detects all sample types and eliminates method **Ultraclean Fluoronetic Z-rail** timing variables - True fluoropolymer action **Exhausted Enclosure** - Magnetically coupled linear drive - Long-lived and chemically resistant Built-in to allow for maximum safety when directly analyzing **Auto Aligning Arm** concentrated chemicals and PFA Probe Sample Containers <1 mL up to 500 mL Overflowing UPW **Dual Rinse Station Ultrapure Water Valve** Controls UPW flow into and throughout the prepFASTS Micro Sampling Precision loading for micro sample analysis Integrated Ultra-highpurity Syringe Dilution Inline automated calibration and dilution system **High Purity** Leak Sensors **PFA Reservoirs** With external warning light and auto-shut-off **Double Containment Tray Reagent Level Sensors**

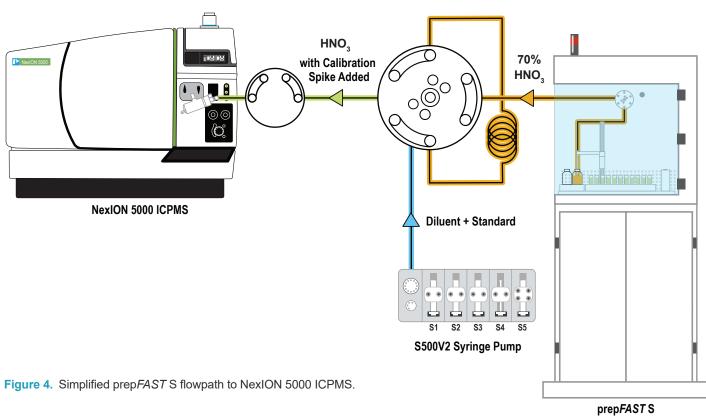
Figure 2. prepFAST S features diagram.

#### Fluorospray Sample Introduction

The Fluorospray sample introduction kit for the NexION 5000 is a new, HF-resistant technology offering enhanced precision and sensitivity for the analysis of semiconductor-grade ultrapure chemicals. Designed for demanding, multichemical

analysis, the Fluorospray chamber combined with an o-ring free Fluorobore platinum injector provides complete high-performance sample introduction for the semiconductor laboratory.





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#### **Experimental: Reagents and Samples**

Commercially available  $\rm HNO_3$  was used as sample for all analyses. A 200 ppt, 1%  $\rm HNO_3$  mixed-element standard was prepared from a 100 ppb standard; Si, P and S were spiked at 200 ppb.

The prepFAST S utilized syringe-driven flow of ultrapure water, semiconductor grade  $\mathsf{HNO}_3,$  and standard solution to automate sample and MSA standard preparation. All MSA standards were prepared from the stock solutions automatically by the prepFAST S. UPW was used as the carrier solution and samples were introduced at 200  $\mu\text{L/min}.$ 

#### **Experimental: Instrumentation**

The NexION 5000 multi-quadrupole ICPMS was used with the Fluorospray sample introduction kit and a microflow PFA-ICN concentric integrated capillary nebulizer. The NexION 5000 automatically switches between cool, warm, and hot plasma conditions to optimize the analysis of all analytes. Cool plasma works in tandem with the multi-quadrupole technology of the NexION 5000 to reduce polyatomic ion interferences while simultaneously reducing background from the ICPMS interface for elements that can be thermally ionized. Hot plasma ensures ionization of refractory and high ionization-potential elements and maintains high matrix tolerance, allowing for analysis of nearly the entire periodic table. Combining multiple plasma conditions, QQQQ filtering and DRC technology allows for excellent detection limits and accurate determination of trace metals in semiconductor chemicals. Instrumental parameters and sample introduction hardware are listed in Table 1. NexION method parameters are shown in Table 2. DRC gas flow rates and RPq values were determined experimentally.

Table 1. Operating Parameters for HNO<sub>3</sub>.

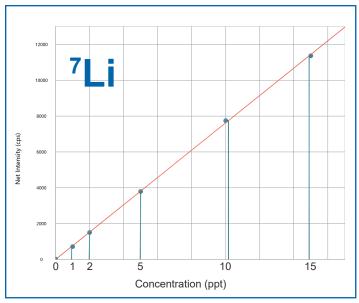
Parameter	Cool Plasma (DRC)	Warm Plasma (DRC)	Hot Plasma (DRC)	Hot Plasma (STD)		
ICP RF Power (W)	600	1000	900	1600		
Nebulizer Gas Flow (L/min)	0.88	0.88	0.85	1		
Reaction Gas	100% NH <sub>3</sub>	100% O <sub>2</sub>	100% NH <sub>3</sub>	-		
AMS Gas Flow (L/min)	0.3					
Auxiliary Gas Flow (L/min)	1.2					
Plasma Gas Flow (L/min)	16					
Sample Flow Rate (mL/min)	0.2					
Nebulizer	Fluoroneb PFA-ICN					
Spray Chamber	Fluorospray PFA					
Torch	SilQ Ultra High Purity Quartz					
Injector	Fluorobore Straight-bore 2.5 mm Platinum					
ICPMS Cones	Platinu	Platinum-tipped Sampler and Skimmer with Nickel Hyperskimmer				
Hyperskimmer Voltage	-30	-50	5			
OmniRing Voltage	-220	-210	-160	-165		
Inner Target Lens Voltage	6					
Outer Target Lens Voltage	0 -17			17		

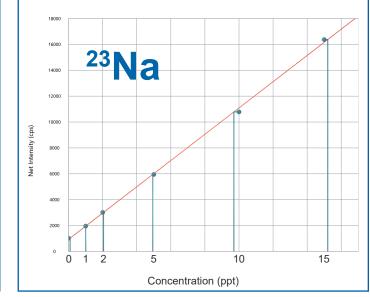
Table 2. ICPMS Analytical Conditions.

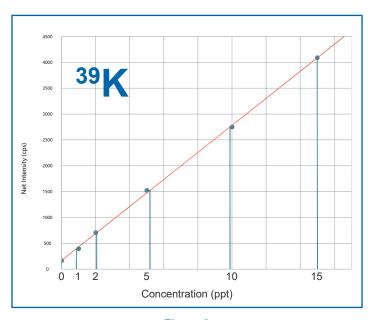
Element	Q1 Mass	Q3 Mass	Power (W)	Reaction Gas	Reaction Gas Flow	QID Fixed	RPq	Axial Field
	-	-	000	<b>N</b> 11.1	0.4	Voltage	0.45	Voltage
Li	7	7	600	NH <sub>3</sub>	0.1	-18	0.45	125
В	11	11	1600	-	0	-16.5	0.25	0
Na	23	23	600	NH <sub>3</sub>	1.2	-18	0.45	125
Mg	24	24	600	NH <sub>3</sub>	1.2	-18	0.45	125
Al	27	27	600	NH <sub>3</sub>	1.2	-18	0.45	125
Si	28	44	1000	0,	3	-16	0.1	150
Р	31	47	1000	O <sub>2</sub>	3	-16	0.1	150
S	32	48	1000	02	3	-16	0.1	150
K	39	39	600	NH <sub>3</sub>	1.2	-18	0.8	125
Ca	40	40	600	NH <sub>3</sub>	1.2	-18	0.8	125
Sc	45	61	1000	02	1	-16	0.45	150
Ti	48	64	1000	O <sub>2</sub>	1	-16	0.1	150
V	51	67	1000	0,	1	-16	0.1	150
Cr	52	52	600	NH <sub>3</sub>	1.2	-18	0.8	125
Mn	55	55	600	NH <sub>3</sub>	1.2	-18	0.8	125
Fe	56	56	600	NH <sub>3</sub>	1.2	-18	0.8	125
Ni	58	58	600	NH <sub>3</sub>	1.2	-18	0.8	125
Со	59	110	900	NH <sub>3</sub>	1	-18	0.3	125
Cu	63	63	600	NH <sub>3</sub>	1.2	-18	0.45	125
Zn	64	64	600	NH <sub>3</sub>	1.2	-18	0.45	125
Ga	71	71	1600	-	0	-16.5	0.25	0
As	75	91	1000	$O_2$	1	-16	0.1	150
Sr	88	88	1600	-	0	-16.5	0.25	0
Υ	89	89	1600	-	0	-16.5	0.25	0
Zr	90	90	1600	-	0	-16.5	0.25	0
Мо	98	98	1600	-	0	-16.5	0.25	0
Ag	107	107	1600	-	0	-16.5	0.25	0
Cd	111	111	1600	-	0	-16.5	0.25	0
In	115	115	1600	-	0	-16.5	0.25	0
Sn	120	120	1600	-	0	-16.5	0.25	0
Sb	123	123	1600	-	0	-16.5	0.25	0
Ва	138	138	1600	-	0	-16.5	0.25	0
Та	181	181	1600	-	0	-16.5	0.25	0
W	184	184	1600	-	0	-16.5	0.25	0
lr	193	193	1600	-	0	-16.5	0.25	0
Au	197	197	1600	-	0	-16.5	0.25	0
TI	205	205	1600	-	0	-16.5	0.25	0
Pb	208	208	1600	-	0	-16.5	0.25	0
Bi	209	209	1600	-	0	-16.5	0.25	0
U	238	238	1600	-	0	-16.5	0.25	0

### **70% HNO<sub>3</sub>**

Calibrations were automatically performed at 0, 1, 2, 5, 10 and 15 ppt (Si 1000x higher)







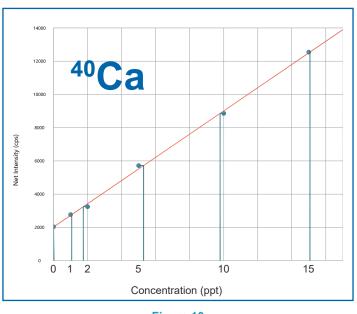
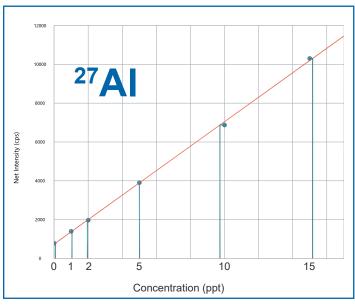


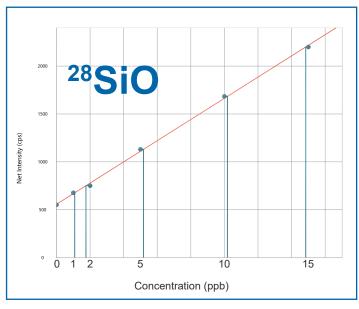


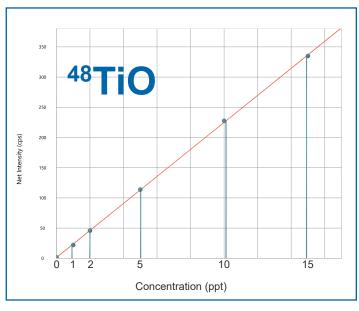
Figure 6

Figure 9

Figure 10







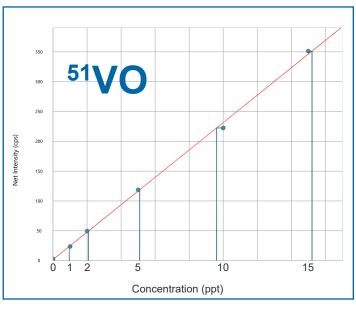


Figure 7

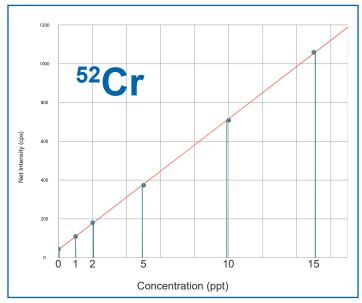
Figure 8

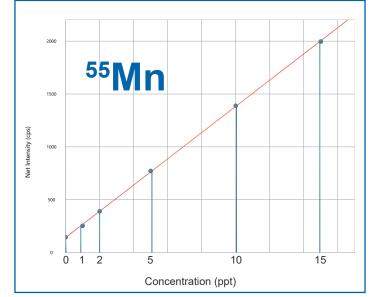
Figure 11

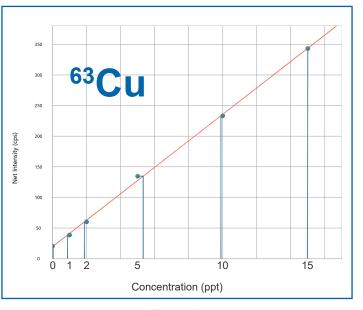
Figure 12

## **70% HNO<sub>3</sub>**

Calibrations were automatically performed at 0, 1, 2, 5, 10 and 15 ppt







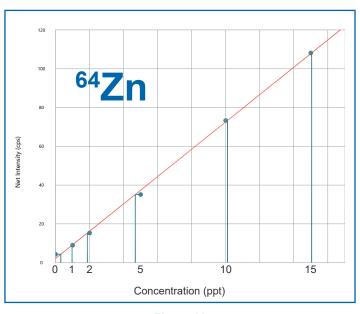
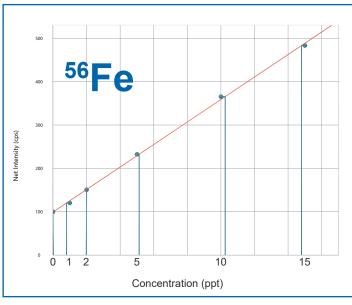


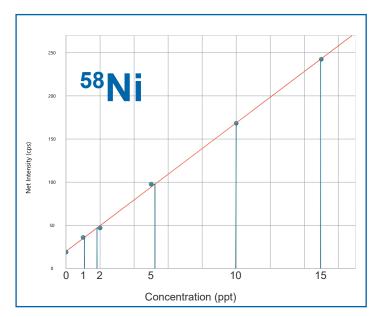


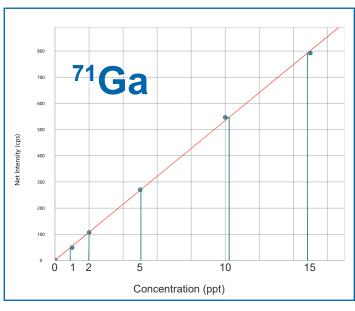
Figure 14

Figure 17

Figure 18







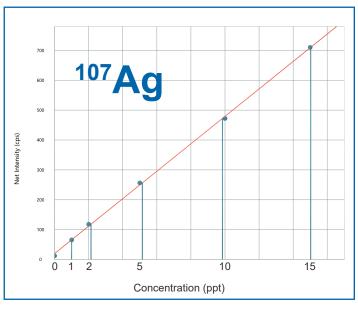


Figure 15

Figure 16

Figure 19

Figure 20

#### **Results and Discussion**

Table 3 shows background equivalent concentrations (BEC), limits of detection (LOD) and correlation coefficient (R) for all elements measured in undiluted HNO<sub>3</sub>. Blank subtraction was not used for the determination of BECs or LODs in this study.

Calibrations were automatically prepared at 0, 1, 2, 5, 10 and 15 ppt automatically with the prep*FAST* S (Si, P and S were spiked at 0, 1, 2, 5, 10 and 15 ppb). Figures 5-20 show calibration curves for a selection of elements with MSA in undiluted HNO<sub>3</sub>.

Combining the prepFAST S with the advantages of various plasma modes, QQQQ filtering and DRC technology allows major contamination-prone elements to be analyzed in the low-ppt range. These advantages make it possible to achieve single-digit-ppt BEC and LOD levels for historically difficult elements such as Na, Mg and Ca in undiluted HNO3. By utilizing the enclosed and vented sampling area in the prepFAST S, these results were achieved in a non-clean room environment. The correlation coefficients demonstrate the accuracy of the prepFAST S automatic dilution and spike addition, which enables calibrations in complicated matrices with excellent results.

Table 3. BECs, Calibration Linearity, and LODs in HNO<sub>3</sub>.

Element	BEC (ppt)	LOD (ppt)	Linearity (R)	Element	BEC (ppt)	LOD (ppt)	Linearity (R)
Li	0.03	0.06	0.999	Ga	0.02	0.1	0.999
В	10.9	10.0	0.999	As	0.06	0.2	0.997
Na	0.7	0.1	0.999	Sr	0.6	0.5	0.999
Mg	1.4	0.6	0.999	Y	1.2	0.2	0.999
Al	1.2	1.2	0.999	Zr	0.7	1.5	0.999
Si (ppb)	5.0	1.8	0.999	Мо	0.4	1.0	0.999
P (ppb)	0.4	0.08	0.999	Ag	0.5	0.7	0.999
S (ppb)	8.1	1.3	0.999	Cd	12.4	2.5	0.998
K	1.7	0.4	0.999	ln	1.2	0.2	0.999
Ca	1.5	1.1	0.999	Sn	1.2	3.1	0.999
Sc	0.09	0.1	0.999	Sb	0.09	0.3	0.999
Ti	0.05	0.1	0.999	Ва	0.3	0.1	0.999
V	0.09	0.2	0.999	Ta	0.02	0.07	0.999
Cr	0.6	0.5	0.999	W	0.1	0.3	0.999
Mn	1.1	1.0	0.999	lr	1.7	2.0	0.999
Fe	3.8	3.6	0.999	Au	0.1	1.2	0.999
Ni	1.3	2.1	0.999	TI	0.1	0.3	0.999
Со	0.3	0.4	0.999	Pb	0.06	0.3	0.999
Cu	0.9	0.6	0.999	Bi	0.2	0.2	0.999
Zn	0.3	1.9	0.999	U	0.03	0.1	0.999

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#### **Conclusions**

Fully automated analysis of Nitric Acid samples was performed using the prepFAST S and NexION 5000 Triple Quad ICPMS. The automated dilution and MSA calibration capabilities of the prepFAST S achieved linear calibration curves for all elements analyzed. The triple quadrupole ICPMS allowed for elimination of key polyatomic interferences, and detection limits for 40 elements were low ppt, while Si, P and S were low ppb.

#### **Summary**

prepFAST S fully automates sample analysis in an ultraclean enclosed system:

- Offers ultrapure semiconductor-grade chemical preparation, dilution, and analysis with detection limits in ppt/ppq range with ICPMS
  - Allows for direct analysis of concentrated chemicals without pre-dilution
- · Automatically performs calibration using MSA or external calibration
- Includes a magnetically coupled PTFE/CTFE drive as part of the most chemically resistant autosampler on the market
- Utilizes SampleSense valve to detect all samples viscous, non-viscous, solvents – without timing or method adjustment



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